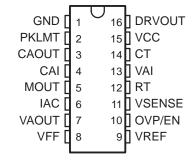


SLUS482B - APRIL 2001 - REVISED DECEMBER 2004

- Controls Boost Preregulator to Near-Unity Power Factor
- World Wide Line Operation
- Over-Voltage Protection
- Accurate Power Limiting
- Average Current Mode Control
- Improved Noise Immunity
- Improved Feed-Forward Line Regulation
- Leading Edge Modulation
- 150-μA Typical Start-Up Current
- Low-Power BiCMOS Operation
- 10.8-V to 17-V Operation
- Programmable Output Voltage (Tracking Boost Topology)

D, DW, N, and PW PACKAGES (TOP VIEW)



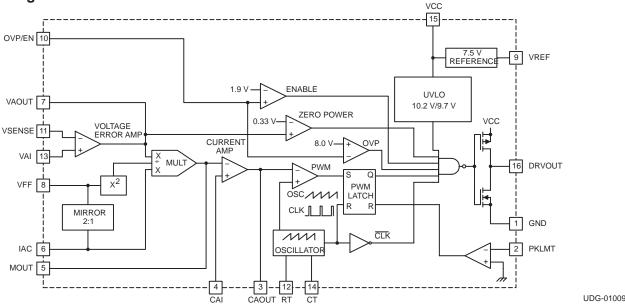
description

The UCC2819/UCC3819 provides all the functions necessary for active power factor corrected preregulators. The controller achieves near unity power factor by shaping the ac-input line current waveform to correspond to that of the ac-input line voltage. Average current mode control maintains stable, low distortion sinusoidal line current.

Designed in Texas Instrument's BiCMOS process, the UCC3819 offers new features such as lower start-up current, lower power dissipation, overvoltage protection, a shunt UVLO detect circuitry and a leading-edge modulation technique to reduce ripple current in the bulk capacitor.

The UCC3819 allows the output voltage to be programmed by bringing out the error amplifier noninverting input. Available in the 16-pin D, DW, N, and PW packages.

block diagram





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



SLUS482B - APRIL 2001 - REVISED DECEMBER 2004

absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

Supply voltage, VCC	V
Gate drive current, continuous 0.2 A	Α
Gate drive current 1.2 A	Α
Input voltage, CAI, MOUT 8 \	V
Input voltage, PKLMT 5 \	V
Input voltage, VSENSE, OVP/EN, VAI	V
Input current, RT, IAC, PKLMT	Α
Maximum negative voltage, DRVOUT, PKLMT, MOUT	V
Power dissipation	٧

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

AVAILABLE OPTIONS

_		PACKAGE DEVICES								
TJ	D PACKAGE	DW PACKAGE	N PACKAGE	PW PACKAGE						
0°C to 70°C	UCC3819D	UCC3819DW	UCC3819N	UCC3819PW						
-40°C to 85°C	UCC2819D	UCC2819DW	UCC2819N	UCC2819PW						

[†] The D, DW, and PW packages are available taped and reeled. Add TR suffix to device type (e.g. UCC3819DTR) to order quantities of 2500 devices per reel.

electrical characteristics, T_A = 0°C to 70°C for the UCC3819, -40°C to 85°C for the UCC2819, VCC = 12 V, R_T = 22 k Ω , C_T = 270 pF, (unless otherwise noted)

supply current

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Supply current, off	VCC = (VCC turnon threshold -0.3 V)		150	300	μΑ
Supply current, on	VCC = 12 V, No load on DRVOUT	2	4	6	mA

UVLO

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
VCC turnon threshold		9.7	10.2	10.8	V
VCC turnoff threshold		9.4	9.7		V
UVLO hysteresis		0.3	0.5		V

voltage amplifier

PARAMETER	TEST CO	TEST CONDITIONS			MAX	UNITS
VIO	VAOUT = 2.75 V,	VCM = 3.75 V	-15		15	mV
VAI bias current	VAOUT = 2.75 V,	VCM = 3.75 V		50	200	nA
VSENSE bias current	VSENSE = VREF,	VAOUT = 2.5 V		50	200	nA
CMRR	VCM = 1 V to 7.5 V		50	70		dB
Open loop gain	VAOUT = 2 V to 5 V		50	90		dB
High-level output voltage	I _L = -150 μA		5.3	5.5	5.6	V
Low-level output voltage	I _L = 150 μA		0	50	150	mV



electrical characteristics, T_A = 0°C to 70°C for the UCC3819, -40°C to 85°C for the UCC2819, VCC = 12 V, R_T = 22 k Ω , C_T = 270 pF, (unless otherwise noted)

over voltage protection and enable

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Over voltage reference		VREF +0.48	VREF +0.50	VREF +0.52	V
Hysteresis		300	500	600	mV
Enable threshold		1.7	1.9	2.1	V
Enable hysteresis		0.1	0.2	0.3	V

current amplifier

PARAMETER	TES	TEST CONDITIONS			MAX	UNITS
Input offset voltage	V _{CM} = 0 V,	VCAOUT = 3 V	-3.5	0	2.5	mV
Input bias current	V _{CM} = 0 V,	VCAOUT = 3 V		-50	-100	nA
Input offset current	V _{CM} = 0 V,	VCAOUT = 3 V		25	100	nA
Open loop gain	V _{CM} = 0 V,	VCAOUT = 2 V to 5 V	90			dB
Common-mode rejection ratio	$V_{CM} = 0 \text{ V to } 1.5 \text{ V},$	V _{CAOUT} = 3 V	60	80		dB
High-level output voltage	I _L = -120 μA		5.6	6.5	6.8	V
Low-level output voltage	I _L = 1 mA		0.1	0.2	0.5	V
Gain bandwidth product	See Note 1			2.5		MHz

voltage reference

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Input voltage, (UCC3819)	$T_A = 0$ °C to 70°C	7.387	7.5	7.613	V
Input voltage, (UCC2819)	$T_A = -40$ °C to 85°C	7.369	7.5	7.631	V
Load regulation	IREF = 1 mA to 2 mA	0		10	mV
Line regulation	VCC = 10.8 V to 15 V, See Note 2	0		10	mV
Short-circuit current	V _{REF} = 0 V	-20	-25	-50	mA

oscillator

PARAMETER	TE	TEST CONDITIONS			TYP	MAX	UNITS
Initial accuracy	T _A = 25°C			85	100	115	kHz
Voltage stability	VCC = 10.8 V to 15 V			-1		1	%
Total variation	Line, temp,	See Note 1		80		120	kHz
Ramp peak voltage				4.5	5	5.5	V
Ramp amplitude voltage (peak to peak)				3.5	4	4.5	V

NOTES: 1. Ensured by design, Not production tested.

2. Reference variation for V_{CC} < 10.8 V is shown in Figure 2.



SLUS482B - APRIL 2001 - REVISED DECEMBER 2004

electrical characteristics, T_A = 0°C to 70°C for the UCC3819, -40°C to 85°C for the UCC2819, VCC = 12 V, R_T = 22 k Ω , C_T = 270 pF, (unless otherwise noted)

peak current limit

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
PKLMT reference voltage		-15		15	mV
PKLMT propagation delay		150	350	500	ns

multiplier

PARAMETER		TEST CONDITI	ONS	MIN	TYP	MAX	UNITS
I _{MOUT} , high line, low power output current, (0°C to 85°C)	$I_{AC} = 500 \mu A$,	$V_{FF} = 4.7 V$,	VAOUT = 1.25 V	0	-6	-20	μΑ
I _{MOUT} , high line, low power output current, (–40°C to 85°C)	$I_{AC} = 500 \mu A$,	$V_{FF} = 4.7 V$,	VAOUT = 1.25 V	0		-23	μΑ
I _{MOUT} , high line, high power output current	I _{AC} = 500 μA,	V _{FF} = 4.7 V,	VAOUT = 5 V	-70	-90	-105	μА
I _{MOUT} , low line, low power output current	I _{AC} = 150 μA,	V _{FF} = 1.4 V,	VAOUT = 1.25 V	-10	-19	-50	μΑ
I _{MOUT} , low line, high power output current	I _{AC} = 150 μA,	$V_{FF} = 1.4 V,$	VAOUT = 5 V	-268	-300	-346	μΑ
I _{MOUT} , IAC limited	$I_{AC} = 150 \mu A$	$V_{FF} = 1.3 V$,	VAOUT = 5 V	-250	-300	-400	μΑ
Gain constant (K)	$I_{AC} = 300 \mu A$	$V_{FF} = 3 V$,	VAOUT = 2.5 V	0.5	1	1.5	1/V
	$I_{AC} = 150 \mu\text{A},$	$V_{FF} = 1.4 V$,	VAOUT = 0.25 V		0	-2	μА
I _{MOUT} , zero current	$I_{AC} = 500 \mu A$	$V_{FF} = 4.7 V$	VAOUT = 0.25 V		0	-2	μΑ
I _{MOUT} , zero current, (0°C to 85°C)	I _{AC} = 500 μA,	$V_{FF} = 4.7 V$,	VAOUT = 0.5 V		0	-3	μА
I _{MOUT} , zero current, (-40°C to 85°C)	I _{AC} = 500 μA,	$V_{FF} = 4.7 V$,	VAOUT = 0.5 V		0	-3.5	μА
Power limit (I _{MOUT} x V _{FF})	$I_{AC} = 150 \mu\text{A},$	V _{FF} = 1.4 V,	VAOUT = 5 V	-375	-420	-485	μW

feed-forward

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
VFF output current	$I_{AC} = 300 \mu\text{A}$	-140	-150	-160	μΑ

gate driver

PARAMETER		TEST CONDI	MIN	TYP	MAX	UNITS	
Pullup resistance	$I_{O} = -100 \text{ mA to } -$	–200 mA			5	12	Ω
Pulldown resistance	I _O = 100 mA				2	10	Ω
Output rise time	C _L = 1 nF,	$R_L = 10 \Omega$,	$V_{DRVOUT} = 0.7 V \text{ to } 9 V$		25	50	ns
Output fall time	C _L = 1 nF,	$R_L = 10 \Omega$,	V _{DRVOUT} = 9 V to 0.7 V		10	50	ns
Maximum duty cycle				93	95	100	%
Minimum controlled duty cycle	At 100 kHz					2	%

zero power

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Zero power comparator threshold	Measured on VAOUT	0.20	0.33	0.50	V



pin descriptions

CAI: (current amplifier noninverting input) Place a resistor between this pin and the GND side of current-sense resistor. This input and the inverting input (MOUT) remain functional down to and below GND.

CAOUT: (current amplifier output) This is the output of a wide bandwidth operational amplifier that senses line current and commands the PFC pulse-width modulator (PWM) to force the correct duty cycle. Compensation components are placed between CAOUT and MOUT.

CT: (oscillator timing capacitor) A capacitor from CT to GND sets the PWM oscillator frequency according to:

$$f \approx \left(\frac{0.6}{RT \times CT}\right)$$

The lead from the oscillator timing capacitor to GND should be as short and direct as possible.

DRVOUT: (gate drive) The output drive for the boost switch is a totem-pole MOSFET gate driver on DRVOUT. Use a series gate resistor to prevent interaction between the gate impedance and the output driver that might cause the DRVOUT to overshoot excessively. See characteristic curve (Figure 13) to determine minimum required gate resister value. Some overshoot of the DRVOUT output is always expected when driving a capacitive load.

GND: (ground) All voltages measured with respect to ground. VCC and REF should be bypassed directly to GND with a 0.1- μ F or larger ceramic capacitor.

IAC: (current proportional to input voltage) This input to the analog multiplier is a current proportional to instantaneous line voltage. The multiplier is tailored for very low distortion from this current input (I_{IAC}) to multiplier output. The recommended maximum I_{IAC} is 500 μ A.

MOUT: (multiplier output and current amplifier inverting input) The output of the analog multiplier and the inverting input of the current amplifier are connected together at MOUT. As the multiplier output is a current, this is a high-impedance input so the amplifier can be configured as a differential amplifier. This configuration improves noise immunity and allows for the leading-edge modulation operation. The multiplier output current is limited to $(2 \times I_{AC})$. The multiplier output current is given by the equation:

$$I_{MOUT} = \frac{I_{IAC} \times (V_{VAOUT} - 1)}{V_{VFF}^2 \times K}$$

where $K = \frac{1}{V}$ is the multiplier gain constant.

OVP/EN: (over-voltage/enable) A window comparator input that disables the output driver if the boost output voltage is a programmed level above the nominal or disables both the PFC output driver and resets SS if pulled below 1.9 V (typ).

PKLMT: (PFC peak current limit) The threshold for peak limit is 0 V. Use a resistor divider from the negative side of the current sense resistor to VREF to level shift this signal to a voltage level defined by the value of the sense resistor and the peak current limit. Peak current limit is reached when PKLMT voltage falls below 0 V.

RT: (oscillator charging current) A resistor from RT to GND is used to program oscillator charging current. A resistor between 10 k Ω and 100 k Ω is recommended. Nominal voltage on this pin is 3 V.



SLUS482B - APRIL 2001 - REVISED DECEMBER 2004

pin descriptions (continued)

VAI: (voltage amplifier non-inverting input) This input can be tied to the VREF or any other voltage reference (\leq 7.5 V) to set the boost regulator output voltage.

VAOUT: (voltage amplifier output) This is the output of the operational amplifier that regulates output voltage. The voltage amplifier output is internally limited to approximately 5.5 V to prevent overshoot.

VCC: (positive supply voltage) Connect to a stable source of at least 20 mA between 10 V and 17 V for normal operation. Bypass VCC directly to GND to absorb supply current spikes required to charge external MOSFET gate capacitances. To prevent inadequate gate drive signals, the output devices are inhibited unless V_{VCC} exceeds the upper under-voltage lockout voltage threshold and remains above the lower threshold.

VFF: (feed-forward voltage) The RMS voltage signal generated at this pin by mirroring 1/2 of the I_{IAC} into a single pole external filter. At low line, the VFF roll should be 14 V.

VSENSE: (voltage amplifier inverting input) This is normally connected to a compensation network and to the boost converter output through a divider network.

VREF: (voltage reference output) VREF is the output of an accurate 7.5-V voltage reference. This output is capable of delivering 20 mA to peripheral circuitry and is internally short-circuit current limited. VREF is disabled and remains at 0 V when V_{VCC} is below the UVLO threshold. Bypass VREF to GND with a 0.1- μ F or larger ceramic capacitor for best stability. Please refer to Figures 8 and 9 for VREF line and load regulation characteristics.

APPLICATION INFORMATION

The UCC3819 is based on the UCC3818 PFC preregulator. For a more detailed application information for this part, please refer to the UCC3818 datasheet product folder.

The main difference between the UCC3818 and the UCC3819 is that the non-inverting input of the voltage error amplifier is made available to the user through an external pin (VAI) in the UCC3819. The SS pin and function were eliminated to accommodate this change.

The benefit of VAI pin is that it can be used to dynamically change the PFC output voltage based on the line voltage (RMS) level or other conditions. Figure 1 shows one suggested implementation of the tracking boost PFC converter as this approach is sometimes referred to. The VAI pin is tied to the VFF pin and hence output voltage scales up with the line voltage. The benefit of this approach is that at lower line voltages the output voltage is lower and that leads to smaller boost inductor value, lower MOSFET conduction losses and reduced component stresses. In order for this feature to work, the downstream converter has to operate over a wider input range.



APPLICATION INFORMATION

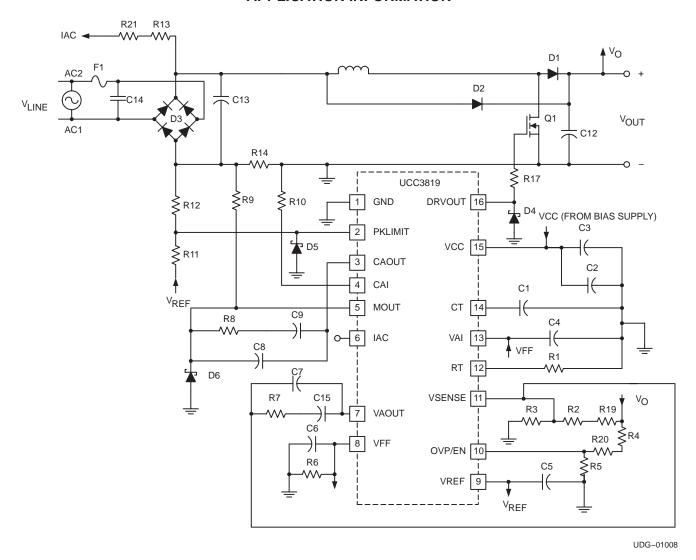


Figure 1. Suggested Implementation of UCC3819 in a Tracking Boost PFC Preregulator

APPLICATION INFORMATION

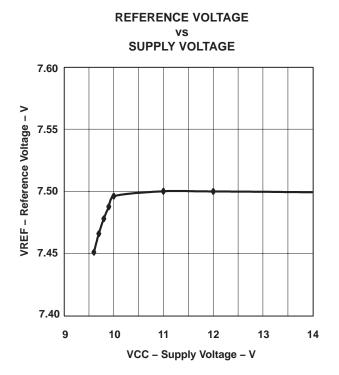


Figure 2

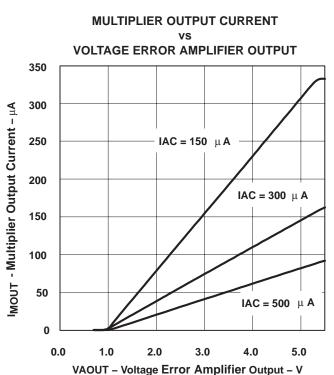


Figure 4

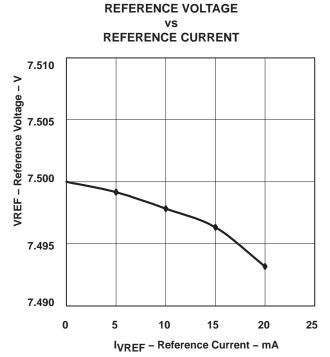


Figure 3

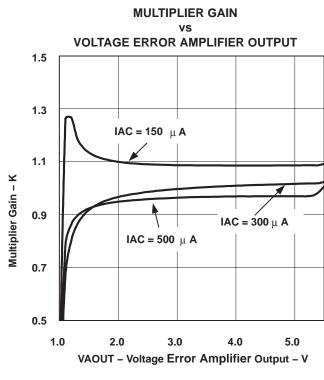


Figure 5



APPLICATION INFORMATION

MULTIPLIER CONSTANT POWER PERFORMANCE

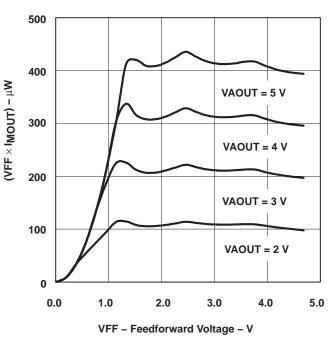


Figure 6

RECOMMENDED MINIMUM GATE RESISTANCE

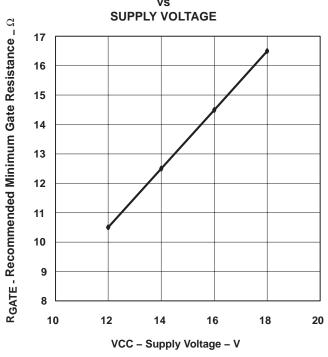


Figure 7







.com 28-Aug-2008

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
UCC2819D	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
UCC2819DG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
UCC2819DTR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
UCC2819DTRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
UCC2819N	ACTIVE	PDIP	N	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type
UCC2819NG4	ACTIVE	PDIP	N	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type
UCC3819N	ACTIVE	PDIP	N	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type
UCC3819NG4	ACTIVE	PDIP	N	16	25	Green (RoHS & no Sb/Br)	CU NIPDAU	N / A for Pkg Type

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device		Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
UCC2819DTR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1





*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
UCC2819DTR	SOIC	D	16	2500	333.2	345.9	28.6

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components which meet ISO/TS16949 requirements, mainly for automotive use. Components which have not been so designated are neither designed nor intended for automotive use; and TI will not be responsible for any failure of such components to meet such requirements.

Products Applications

Audio Automotive and Transportation www.ti.com/automotive www.ti.com/audio **Amplifiers** amplifier.ti.com Communications and Telecom www.ti.com/communications **Data Converters** dataconverter.ti.com Computers and Peripherals www.ti.com/computers DI P® Products Consumer Electronics www.dlp.com www.ti.com/consumer-apps

DSP dsp.ti.com **Energy and Lighting** www.ti.com/energy Clocks and Timers www.ti.com/clocks Industrial www.ti.com/industrial Interface Medical www.ti.com/medical interface.ti.com Logic logic.ti.com Security www.ti.com/security

Power Mgmt power.ti.com Space, Avionics and Defense www.ti.com/space-avionics-defense

Microcontrollers microcontroller.ti.com Video and Imaging www.ti.com/video

RFID www.ti-rfid.com

OMAP Applications Processors <u>www.ti.com/omap</u> TI E2E Community <u>e2e.ti.com</u>

Wireless Connectivity <u>www.ti.com/wirelessconnectivity</u>